

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC367F, TC74VHC367FN, TC74VHC367FT
TC74VHC368F, TC74VHC368FN, TC74VHC368FT

HEX BUS BUFFER

TC74VHC367 F / FN / FT
TC74VHC368 F / FN / FTNON - INVERTED, 3 - STATE OUTPUTS
INVERTED, 3 - STATE OUTPUTS

(Note) The JEDEC SOP (FN) is not available in Japan.

The TC74VHC367 and 368 are advanced high speed CMOS HEX BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ($\overline{G1}$), and the other two buffers are controlled by another enable input ($\overline{G2}$). The outputs of each buffer group are enabled when $\overline{G1}$ and/or $\overline{G2}$ inputs are held low; if held high, these outputs are in a high impedance state.

The TC74VHC367 is a non-inverting output type, while the TC74VHC368 is an inverting output type.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES:

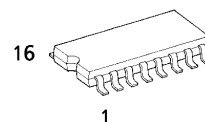
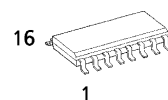
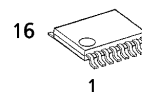
- High Speed..... $t_{pd} = 3.8\text{ns}(\text{typ.})$ at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range..... $V_{CC} (\text{opr}) = 2\text{V} \sim 5.5\text{V}$
- Low Noise..... $V_{OLP} = 0.8\text{V} (\text{Max.})$
- Pin and Function Compatible with 74ALS367/368

TRUTH TABLE

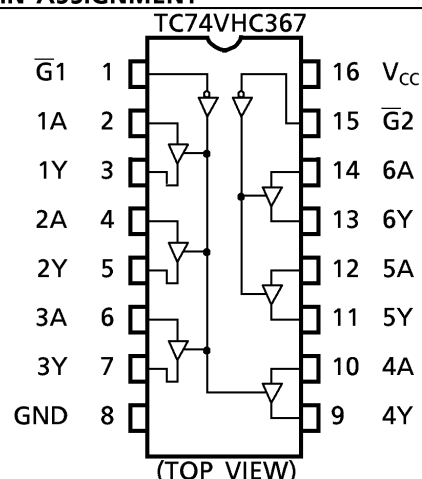
INPUTS		OUTPUTS	
$\overline{G}$	A	Y(367)	$\overline{Y}$ (368)
L	L	L	H
L	H	H	L
H	X	Z	Z

X : Don't Care

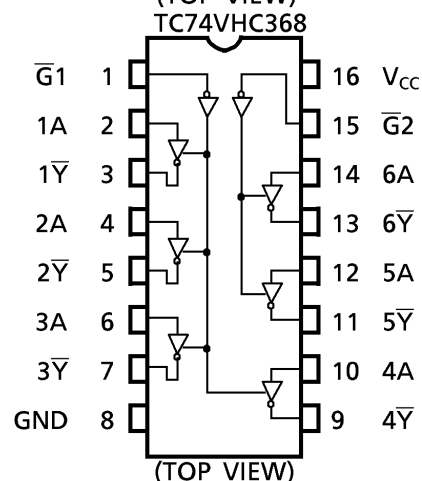
Z : High Impedance

F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)FN (SOL16-P-150-1.27)
Weight : 0.13g (Typ.)FT (TSSOP16-P-0044-0.65)
Weight : 0.06g (Typ.)

PIN ASSIGNMENT



(TOP VIEW)

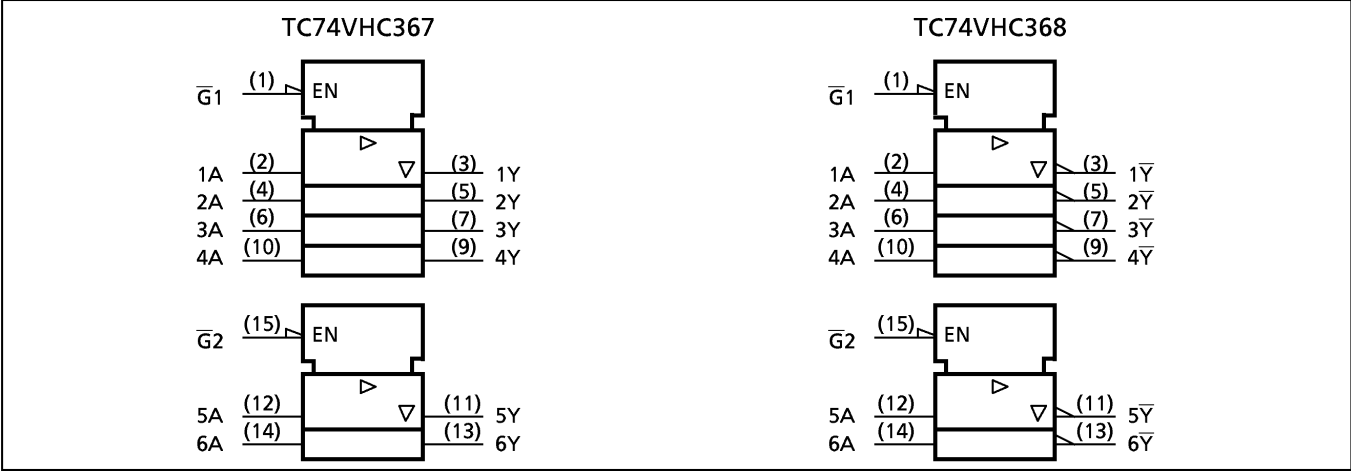


(TOP VIEW)

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IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7.0$	V
DC Input Voltage	V_{IN}	$-0.5 \sim 7.0$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	$^{\circ}\text{C}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	$-40 \sim 85$	$^{\circ}\text{C}$
Input Rise and Fall Time	dt/dv	0~100 ($V_{CC} = 3.3 \pm 0.3\text{V}$) 0~20 ($V_{CC} = 5 \pm 0.5\text{V}$)	ns / V

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V _{IH}			2.0 3.0~ 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	— —	V
Low - Level Input Voltage	V _{IL}			2.0 3.0~ 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50μA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —	V
			I _{OH} = -4mA	3.0	2.58	—	—	2.48	—	
			I _{OH} = -8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50μA	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			I _{OL} = 4mA	3.0	—	—	0.36	—	0.44	
			I _{OL} = 8mA	4.5	—	—	0.36	—	0.44	
3 - State Output Off - State Current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~5.5	—	—	±0.1	—	±1.0	
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—	40.0	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = − 40~85°C		UNIT
			V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (TC74VHC367)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	5.9	8.3	1.0	10.0	ns
				50	—	8.4	11.8	1.0	13.5	
			5.0 ± 0.5	15	—	4.1	5.9	1.0	7.0	
				50	—	5.6	7.9	1.0	9.0	
Propagation Delay Time (TC74VHC368)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	5.3	7.5	1.0	9.0	
				50	—	7.8	11.0	1.0	12.5	
			5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	
				50	—	5.3	7.5	1.0	8.5	
3-State Output Enable Time	t_{pZL} t_{pZH}	RL = 1kΩ	3.3 ± 0.3	15	—	6.8	10.5	1.0	12.5	
				50	—	9.3	14.0	1.0	16.0	
			5.0 ± 0.5	15	—	4.8	7.2	1.0	8.5	
				50	—	6.3	9.2	1.0	10.5	
3-State Output Disable Time	t_{pLZ} t_{pHZ}	RL = 1kΩ	3.3 ± 0.3	50	—	9.9	13.6	1.0	15.5	
			5.0 ± 0.5	50	—	6.3	9.2	1.0	10.5	
Output to Output Skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input Capacitance	C _{I N}				—	4	10	—	10	pF
Output Capacitance	C _{OUT}				—	6	—	—	—	
Power Dissipation Capacitance	C _{PD}	(Note 2)			—	19	—	—	—	

Note (1) Parameter guaranteed by design. $t_{osLH} = t_{pLHm} - t_{pLHn}$, $t_{osHL} = t_{pHLm} - t_{pHLn}$

Note (2) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

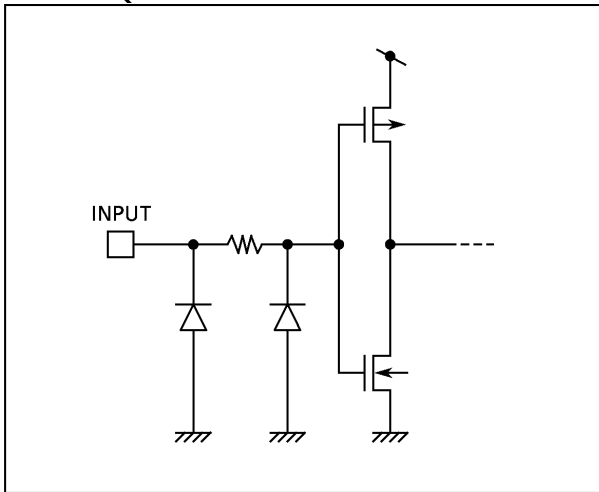
Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per bit)}$$

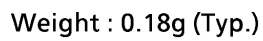
NOISE CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		UNIT
				V _{CC} (V)	TYP. MAX.	
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF		5.0	0.4 0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF		5.0	-0.4 -0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF		5.0	— 3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF		5.0	— 1.5	V

INPUT EQUIVALENT CIRCUIT



Unit in mm



Unit in mm

Weight : 0.13g (Typ.)

TSSOP 16PIN OUTLINE DRAWING (TSSOP16-P-0044-0.65)

Unit in mm

